EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	13	transadmittance near3 voltage	US-PGPUB; USPAT	ADJ	ON	2007/12/31 10:25
\$2	480	(transadmittance or transconductance) and negative resistance	US-PGPUB; USPAT	ADJ	ON	2007/12/31 10:44
S3	329	(transadmittance or transconductance) and negative resistance and voltage near2 current	US-PGPUB; USPAT	ADJ	ON	2007/12/31 10:59
S4	75	(transadmittance or transconductance) and negative resistance and "327".clas.	US-PGPUB; USPAT	ADJ	ON	2007/12/31 11:01
S5	78	(transadmittance or transconductance) and negative resistance and ("323".clas. or "327".clas.)	US-PGPUB; USPAT	ADJ	ON	2007/12/31 13:10
S6	350	327/103.ccls.	US-PGPUB; USPAT	ADJ	ON	2007/12/31 13:29
S7	222	327/103.ccls. and differential	US-PGPUB; USPAT	ADJ	ON	2007/12/31 13:30
 S8	0	voltage near2 to near2 current and variable resist\$5	US-PGPUB; USPAT	ADJ	ON	2007/12/31 14:37
S9	0	voltage near2 to near2 current	US-PGPUB; USPAT	ADJ	ON	2007/12/31 14:37
S10	1427	((voltage to current) or (voltage-to-current) or transadmittance or transconductance) and variable resist\$5	US-PGPUB; USPAT	ADJ	ON	2007/12/31 14:38
S11	2492	326/93-98.ccls.	US-PGPUB; USPAT	ADJ	ON	2008/01/03 10:58
S12	1644	326/93-98.ccls. and delay	US-PGPUB; USPAT	ADJ	ON	2008/01/03 11:15
S13	393	326/93-98.ccls. and delay and capacitor	US-PGPUB; USPAT	ADJ	ON	2008/01/03 11:15
S14	51	326/93-98.ccls. and delay and capacitor and master	US-PGPUB; USPAT	ADJ	ON	2008/01/03 15:08

S15	7	master and slave and ((pass near2 gate) (transmission near2 gate)) and S11 and capacitor and delay	US-PGPUB; USPAT	OR	ON	2008/01/03 15:31
S16	10	master and slave and ((pass near2 gate) (transmission near2 gate)) and S11 and capacitor	US-PGPUB; USPAT	OR	ON	2008/01/03 15:39
S17	2588	327/103,552,553,554,555,556,557.ccls.	US-PGPUB; USPAT	ADJ	ON	2008/01/07 16:46
S18	389	S17 and transconduct\$5 and transistor	US-PGPUB; USPAT	ADJ	ON	2008/01/07 16:46
S19	2786	327/103,552,553,554,555,556,557,558,559.ccls.	US-PGPUB; USPAT	ADJ	ON	2008/01/08 07:34
S20	328	327/103,552,553,554,555,556,557,558,559.ccls. and transconductance and transistor and resistor	US-PGPUB; USPAT	ADJ	ON	2008/01/08 07:34
S21	182	327/103,552,553,554,555,556,557,558,559.cds. and gm and transistor and resistor	US-PGPUB; USPAT	ADJ	ON	2008/01/08 08:06
S22	1194	327/103,552,553,554,555,556,557,558,559.cds. and transistor and resistor	US-PGPUB; USPAT	ADJ	ON	2008/01/08 08:19
S2 3	596	327/103,552,553,554,555,556,557,558,559.cds. and transistor and resistor and bias	US-PGPUB; USPAT	ADJ	ON	2008/01/08 08:19
S24	14	327/538,540,541.ccls. and biasing with regulated	US-PGPUB; USPAT	ADJ	ON	2008/01/08 08:40
S25	138	327/538,540,541.cds. and biasing and regulated	US-PGPUB; USPAT	ADJ	ON	2008/01/08 08:41
S26	3077	"330".clas. and transconductance and transistor	US-PGPUB; USPAT	ADJ	ON	2008/01/10 07:57
S27	75	S26 and negative resistance	US-PGPUB; USPAT	ADJ	ON	2008/01/10 07:58
\$28	1	("6608527").PN.	USPAT; USOCR	OR	OFF	2008/01/10 08:12
\$29	75	S26 and negative resistance	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 08:14

S30	78	\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 08:14
S31	2592		US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 08:16
S32	1964	and differential	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 08:17
S33	1959		US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 08:30
S34	242	near2 resist\$5	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 08:31
S35	5171	negative resistance	US-PGPUB; USPAT	ADJ	ON	2008/01/10 09:24
S36	3033	negative resistance and transistor	US-PGPUB; USPAT	ADJ	ON	2008/01/10 09:24
S37	2139	negative resistance and transistor and resistor	US-PGPUB; USPAT	ADJ	ON	2008/01/10 09:24

S38	841	negative resistance and transistor and resistor and differential	US-PGPUB; USPAT	ADJ	ON	2008/01/10 09:25
S39	533476	(voltage near3 current) or gm amplifier or transconductance amplifier and transistor and resistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 10:21
S40	117105	((voltage near3 current) or gm amplifier or transconductance amplifier) and transistor and resistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 10:21
S41	3168	(gm amplifier or transconductance amplifier) and transistor and resistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 10:22
S42	788	(gm amplifier or transconductance amplifier) and transistor and (variable near3 (resist\$5 or voltage))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/01/10 10:23
S43	19	Hori-Shinichi.in.	US-PGPUB; USPAT	ADJ	ON	2008/01/10 16:45

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